TOSHIBA Diodes for Protecting against ESD Epitaxial Planar Type

## DF3A8.2FE

Product for Use Only as Protection against Electrostatic Discharge (ESD)

- \* This product is for protection against electrostatic discharge (ESD) only and is not intended for any other usage, including without limitation, the constant voltage diode application.
- The mounting of two devices on an ultra-compact package allows the number of parts and the mounting cost to be reduced.

### **Absolute Maximum Ratings (Ta = 25°C)**

| Characteristics           | Symbol           | Rating  | Unit |
|---------------------------|------------------|---------|------|
| Power dissipation         | Р                | 100     | mW   |
| Junction temperature      | Tj               | 125     | °C   |
| Storage temperature range | T <sub>stg</sub> | -55~125 | °C   |

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling

Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

# 1. CATHODE1 2. CATHODE2 3. ANODE JEDEC JEITA TOSHIBA 1.6 ± 0.1 0.85 ± 0.1 1.0 ± 0.7 0.85 ± 0.1

Weight: 0.0023 g (typ.)

### **Electrical Characteristics (Ta = 25°C)**

| Characteristics                                  | Symbol         | Test Condition                  | Min | Тур. | Max | Unit |
|--|----------------|---------------------------------|-----|------|-----|------|
| Zener voltage                                    | VZ             | $I_Z = 5 \text{ mA}$            | 7.7 | 8.2  | 8.7 | V    |
| Dynamic impedance                                | Z <sub>Z</sub> | $I_Z = 5 \text{ mA}$            | _   | _    | 20  | Ω    |
| Reverse current                                  | I <sub>R</sub> | V <sub>R</sub> = 5 V            |     |      | 0.5 | μА   |
| Terminal capacitance (between Cathode and Anode) | C <sub>T</sub> | V <sub>R</sub> = 0 V, f = 1 MHz | _   | 38   | _   | pF   |

### **Guaranteed Level of ESD Immunity**

| Test Condition                      | ESD Immunity Level |
|-------------------------------------|--------------------|
| IEC61000-4-2<br>(Contact discharge) | ± 30 kV            |

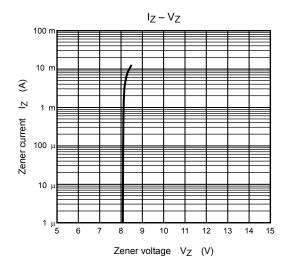
Criterion: No damage to device elements

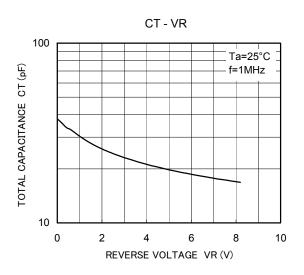
### Marking

# Equivalent Circuit (top view)









### RESTRICTIONS ON PRODUCT USE

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- The information contained herein is subject to change without notice.
- TOSHIBA is continually working to improve the quality and reliability of its products. Nevertheless, semiconductor devices in general can malfunction or fail due to their inherent electrical sensitivity and vulnerability to physical stress. It is the responsibility of the buyer, when utilizing TOSHIBA products, to comply with the standards of safety in making a safe design for the entire system, and to avoid situations in which a malfunction or failure of such TOSHIBA products could cause loss of human life, bodily injury or damage to property. In developing your designs, please ensure that TOSHIBA products are used within specified operating ranges as set forth in the most recent TOSHIBA products specifications. Also, please keep in mind the precautions and conditions set forth in the "Handling Guide for Semiconductor Devices," or "TOSHIBA Semiconductor Reliability Handbook" etc.
- The TOSHIBA products listed in this document are intended for usage in general electronics applications (computer, personal equipment, office equipment, measuring equipment, industrial robotics, domestic appliances, etc.). These TOSHIBA products are neither intended nor warranted for usage in equipment that requires extraordinarily high quality and/or reliability or a malfunction or failure of which may cause loss of human life or bodily injury ("Unintended Usage"). Unintended Usage include atomic energy control instruments, airplane or spaceship instruments, transportation instruments, traffic signal instruments, combustion control instruments, medical instruments, all types of safety devices, etc.. Unintended Usage of TOSHIBA products listed in his document shall be made at the customer's own risk.
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  that regulate the inclusion or use of controlled substances. Toshiba assumes no liability for damage or losses
  occurring as a result of noncompliance with applicable laws and regulations.